



BSS138AKRA-Q

60 V, dual N-channel Trench MOSFET

2 September 2024

Product data sheet

1. General description

Dual N-channel enhancement mode Field-Effect Transistor (FET) in an ultra small DFN1412-6 (SOT1268) leadless Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Logic-level compatible
- Very fast switching
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection
- AEC-Q101 qualified

3. Applications

- Relay driver
- High-speed line driver
- Low-side load switch
- Switching circuits

4. Quick reference data

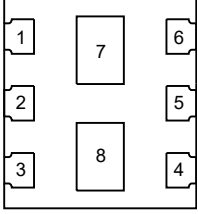
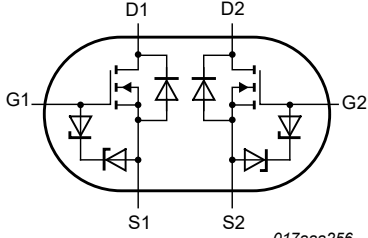
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Per transistor						
V_{DS}	drain-source voltage	$T_j = 25\text{ °C}$	-	-	60	V
V_{GS}	gate-source voltage		-20	-	20	V
I_D	drain current	$V_{GS} = 10\text{ V}; T_{amb} = 25\text{ °C}$	[1]	-	320	mA
Static characteristics						
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10\text{ V}; I_D = 100\text{ mA}; T_j = 25\text{ °C}$	-	2.2	2.9	Ω

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S1	source TR1	 <p>Transparent top view DFN1412-6 (SOT1268)</p>	 <p>017aaa256</p>
2	G1	gate TR1		
3	D2	drain TR2		
4	S2	source TR2		
5	G2	gate TR2		
6	D1	drain TR1		
7	D1	drain TR1		
8	D2	drain TR2		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BSS138AKRA-Q	DFN1412-6	plastic, thin small outline package; no leads; 6 terminals; 1.4 mm x 1.2 mm x 0.47 mm body	SOT1268

7. Marking

Table 4. Marking codes

Type number	Marking code
BSS138AKRA-Q	D4

8. Limiting values

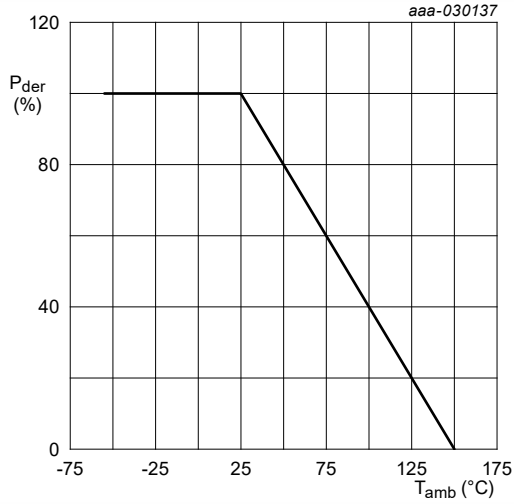
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transistor						
V_{DS}	drain-source voltage	$T_j = 25\text{ °C}$		-	60	V
V_{GS}	gate-source voltage			-20	20	V
I_D	drain current	$V_{GS} = 10\text{ V}; T_{amb} = 25\text{ °C}$	[1]	-	320	mA
		$V_{GS} = 10\text{ V}; T_{amb} = 100\text{ °C}$	[1]	-	200	mA
I_{DM}	peak drain current	$T_{amb} = 25\text{ °C};$ single pulse; $t_p \leq 10\text{ }\mu\text{s}$		-	3.7	A
P_{tot}	total power dissipation	$T_{amb} = 25\text{ °C}$	[2]	-	420	mW
			[1]	-	590	mW
		$T_{sp} = 25\text{ °C}$		-	5	W
Per device						
P_{tot}	total power dissipation	$T_{amb} = 25\text{ °C}$	[2]	-	630	mW
T_j	junction temperature			-55	150	°C
T_{amb}	ambient temperature			-55	150	°C
T_{stg}	storage temperature			-65	150	°C
Source-drain diode (per transistor)						
I_S	source current	$T_{amb} = 25\text{ °C}$	[1]	-	320	mA
ESD maximum rating (per transistor)						
V_{ESD}	electrostatic discharge voltage	HBM		-	500	V
Avalanche ruggedness (per transistor)						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$T_{j(init)} = 25\text{ °C}; I_D = 20\text{ mA};$ DUT in avalanche (unclamped)		-	6.6	mJ

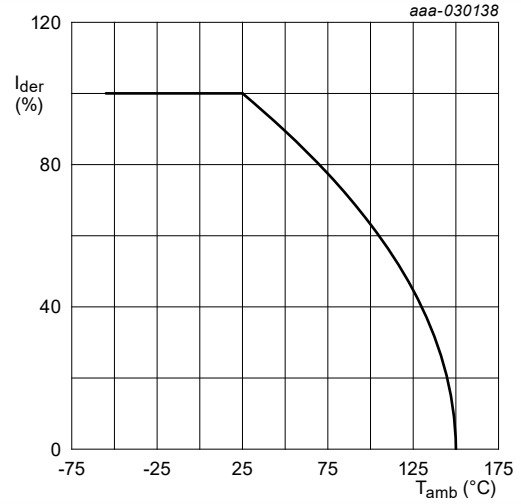
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



$$P_{der} = \frac{P_{tot}}{P_{tot}(25^{\circ}\text{C})} \times 100\%$$

Fig. 1. Normalized total power dissipation as a function of ambient temperature



$$I_{der} = \frac{I_D}{I_D(25^{\circ}\text{C})} \times 100\%$$

Fig. 2. Normalized continuous drain current as a function of ambient temperature

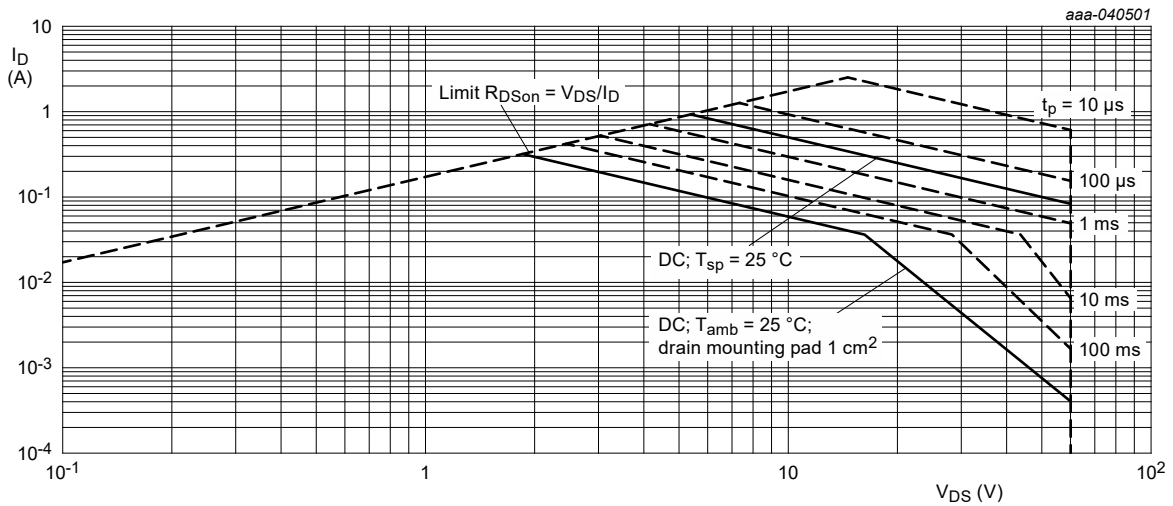


Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	260	300	K/W
			[2]	-	184	212	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		-	20	25	K/W	
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	200	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

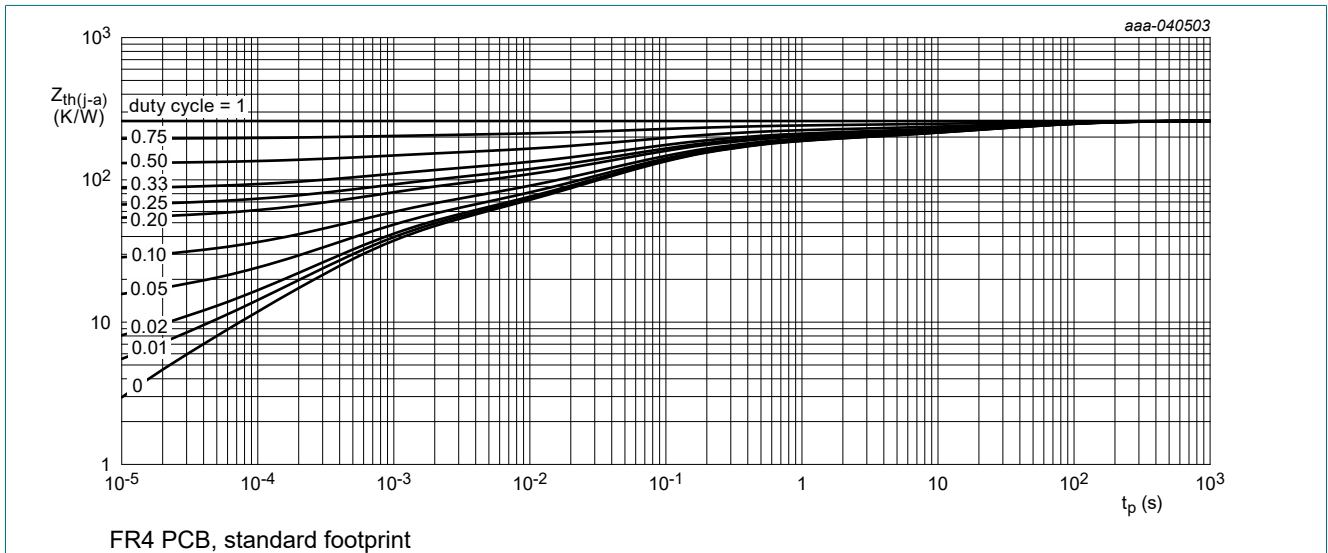


Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

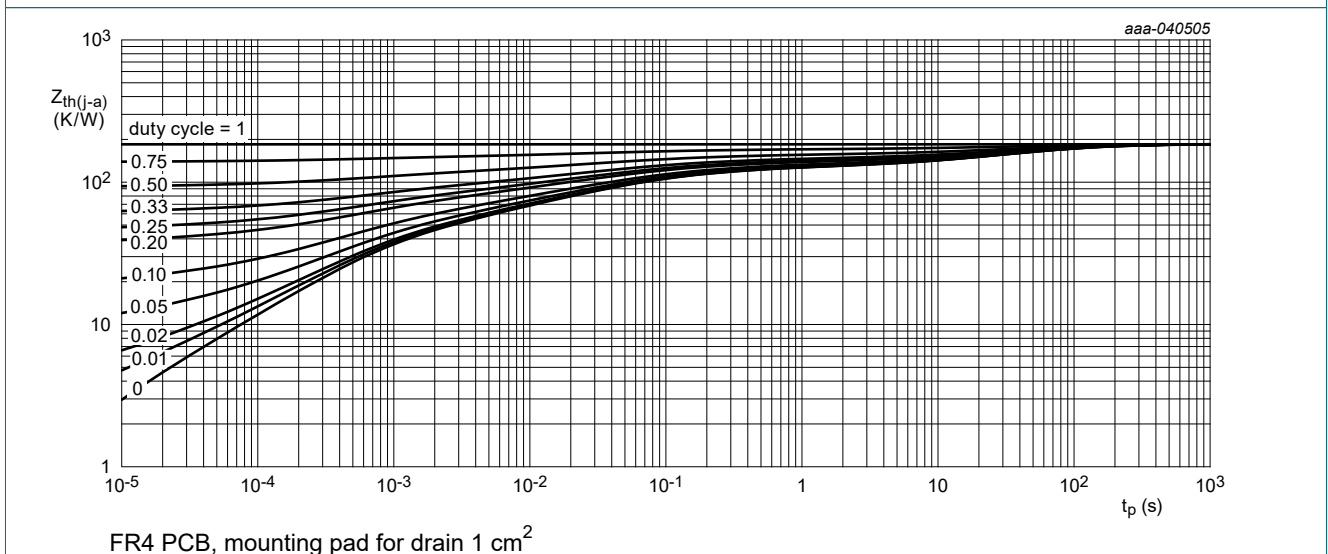


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu A$; $V_{GS} = 0 V$; $T_j = 25 \text{ }^\circ C$	60	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = 250 \mu A$; $V_{DS} = V_{GS}$; $T_j = 25 \text{ }^\circ C$	0.8	1.1	1.5	V
I_{DSS}	drain leakage current	$V_{DS} = 60 V$; $V_{GS} = 0 V$; $T_j = 25 \text{ }^\circ C$	-	-	500	nA
		$V_{DS} = 60 V$; $V_{GS} = 0 V$; $T_j = 125 \text{ }^\circ C$	-	-	5	μA
I_{GSS}	gate leakage current	$V_{GS} = 20 V$; $V_{DS} = 0 V$; $T_j = 25 \text{ }^\circ C$	-	-	10	μA
		$V_{GS} = -20 V$; $V_{DS} = 0 V$; $T_j = 25 \text{ }^\circ C$	-	-	-10	μA
		$V_{GS} = 10 V$; $V_{DS} = 0 V$; $T_j = 25 \text{ }^\circ C$	-	-	1	μA
		$V_{GS} = -10 V$; $V_{DS} = 0 V$; $T_j = 25 \text{ }^\circ C$	-	-	-1	μA
		$V_{GS} = 5 V$; $V_{DS} = 0 V$; $T_j = 25 \text{ }^\circ C$	-	-	500	nA
		$V_{GS} = -5 V$; $V_{DS} = 0 V$; $T_j = 25 \text{ }^\circ C$	-	-	-500	nA
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10 V$; $I_D = 100 \text{ mA}$; $T_j = 25 \text{ }^\circ C$	-	2.2	2.9	Ω
		$V_{GS} = 10 V$; $I_D = 100 \text{ mA}$; $T_j = 150 \text{ }^\circ C$	-	4.4	5.8	Ω
		$V_{GS} = 4.5 V$; $I_D = 50 \text{ mA}$; $T_j = 25 \text{ }^\circ C$	-	2.6	3.7	Ω
		$V_{GS} = 2.5 V$; $I_D = 10 \text{ mA}$; $T_j = 25 \text{ }^\circ C$	-	3.4	12	Ω
g_{fs}	forward transconductance	$V_{DS} = 5 V$; $I_D = 100 \text{ mA}$; $T_j = 25 \text{ }^\circ C$	-	0.3	-	S
Dynamic characteristics						
$Q_{G(tot)}$	total gate charge	$V_{DS} = 30 V$; $I_D = 100 \text{ mA}$; $V_{GS} = 10 V$; $T_j = 25 \text{ }^\circ C$	-	0.21	0.315	nC
Q_{GS}	gate-source charge		-	0.022	-	nC
Q_{GD}	gate-drain charge		-	0.051	-	nC
C_{iss}	input capacitance	$V_{DS} = 30 V$; $f = 1 \text{ MHz}$; $V_{GS} = 0 V$; $T_j = 25 \text{ }^\circ C$	-	9	-	pF
C_{oss}	output capacitance		-	1.8	-	pF
C_{rss}	reverse transfer capacitance		-	1.1	-	pF
$t_{d(on)}$	turn-on delay time	$V_{DS} = 30 V$; $I_D = 100 \text{ mA}$; $V_{GS} = 10 V$; $R_{G(ext)} = 6 \text{ }^\circ \Omega$; $T_j = 25 \text{ }^\circ C$	-	1	-	ns
t_r	rise time		-	1	-	ns
$t_{d(off)}$	turn-off delay time		-	2	-	ns
t_f	fall time		-	3	-	ns
Source-drain diode						
V_{SD}	source-drain voltage	$I_S = 210 \text{ mA}$; $V_{GS} = 0 V$; $T_j = 25 \text{ }^\circ C$	-	1	1.6	V
t_{rr}	reverse recovery time	$I_S = 210 \text{ mA}$; $dI_S/dt = -100 \text{ A}/\mu s$; $V_{GS} = 0 V$; $V_{DS} = 30 V$; $T_j = 25 \text{ }^\circ C$	-	7	-	ns
Q_r	recovered charge		-	1	-	nC

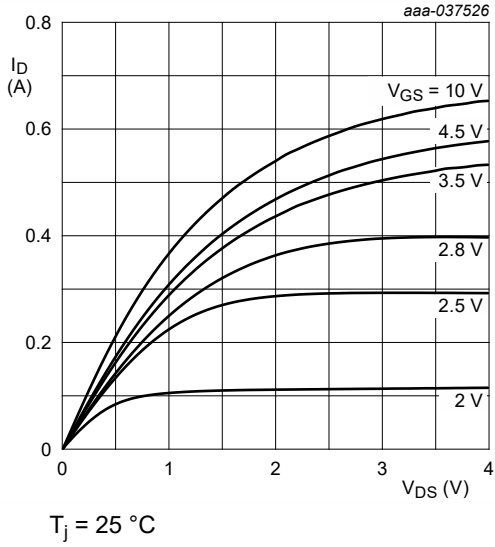


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values

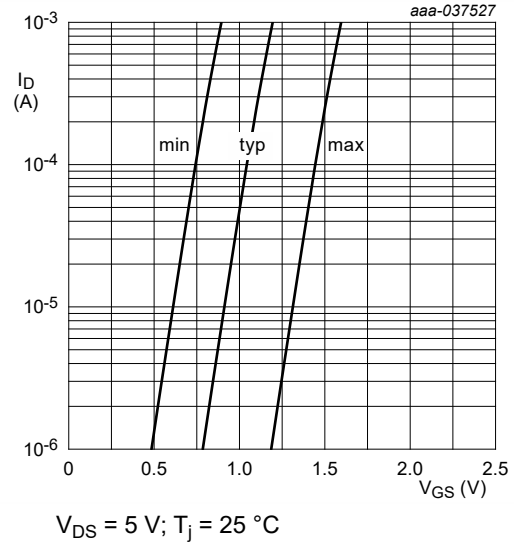


Fig. 7. Sub-threshold drain current as a function of gate-source voltage

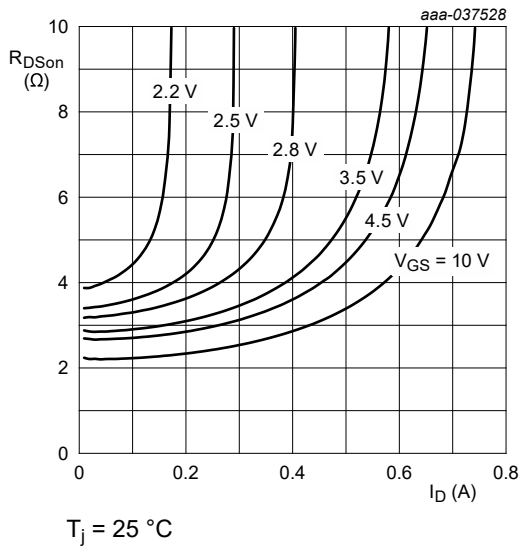


Fig. 8. Drain-source on-state resistance as a function of drain current; typical values

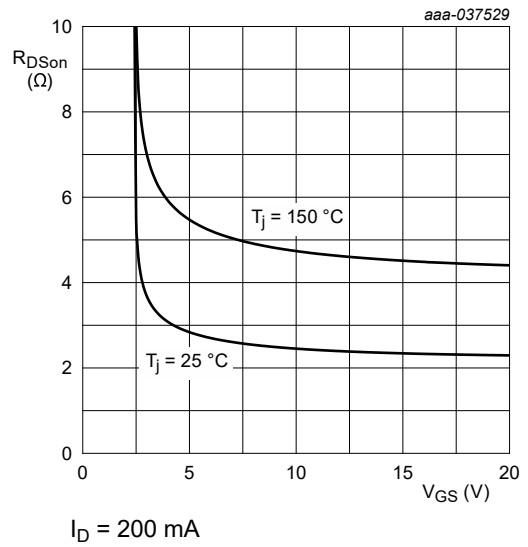


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

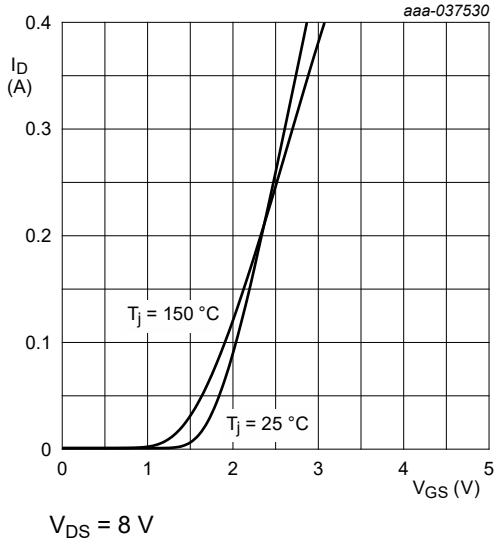


Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

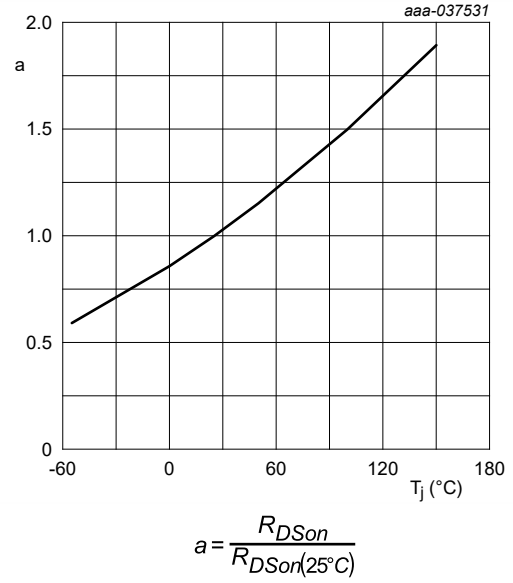


Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

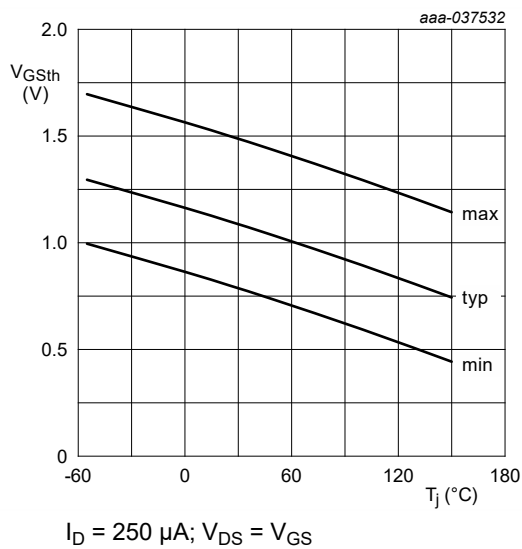


Fig. 12. Gate-source threshold voltage as a function of junction temperature

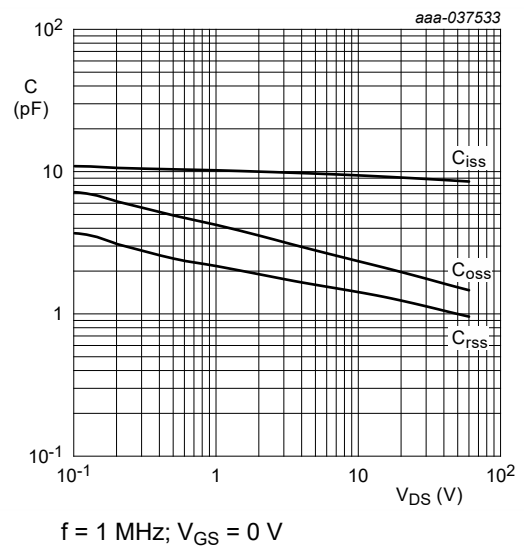
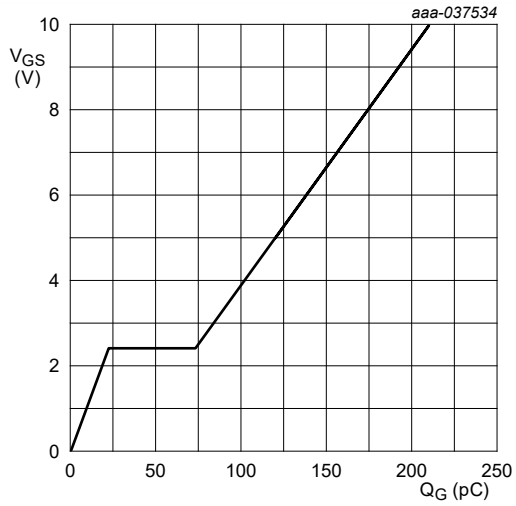


Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



$I_D = 0.23$ A; $V_{DS} = 30$ V; $T_j = 25$ °C

Fig. 14. Gate-source voltage as a function of gate charge; typical values

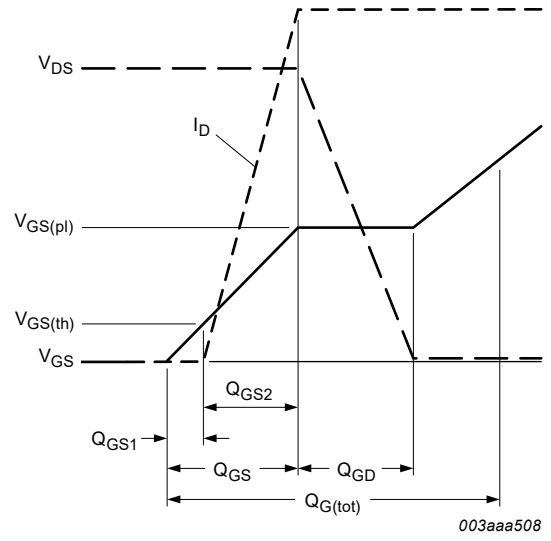
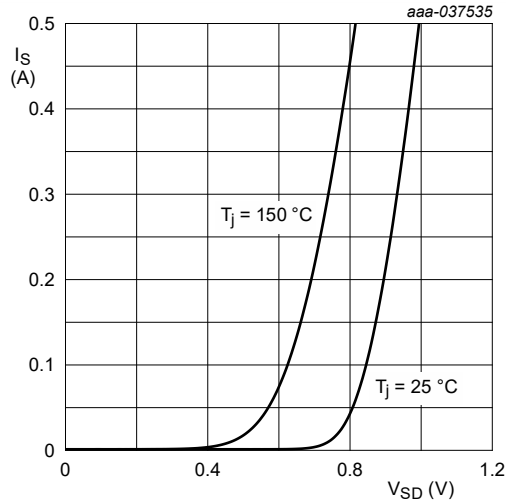


Fig. 15. Gate charge waveform definitions



$V_{GS} = 0$ V

Fig. 16. Source current as a function of source-drain voltage; typical values

11. Test information

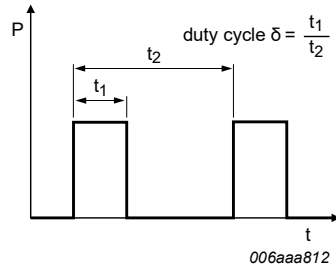


Fig. 17. Duty cycle definition

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline

DFN1412-6: plastic thermal enhanced ultra thin small outline package; no leads;
6 terminals; body: 1.4 x 1.2 x 0.47 mm

SOT1268

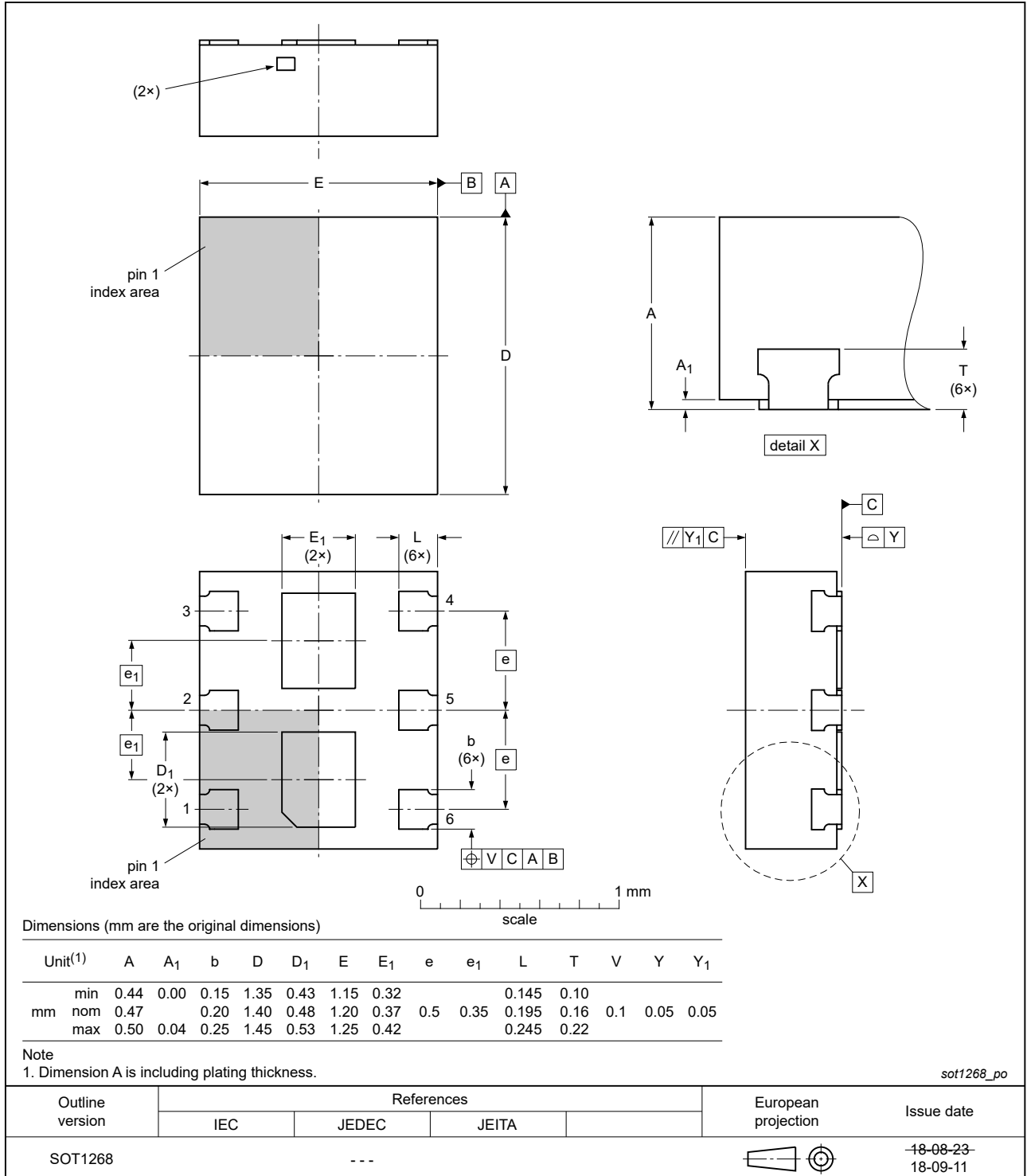


Fig. 18. Package outline DFN1412-6 (SOT1268)

13. Soldering

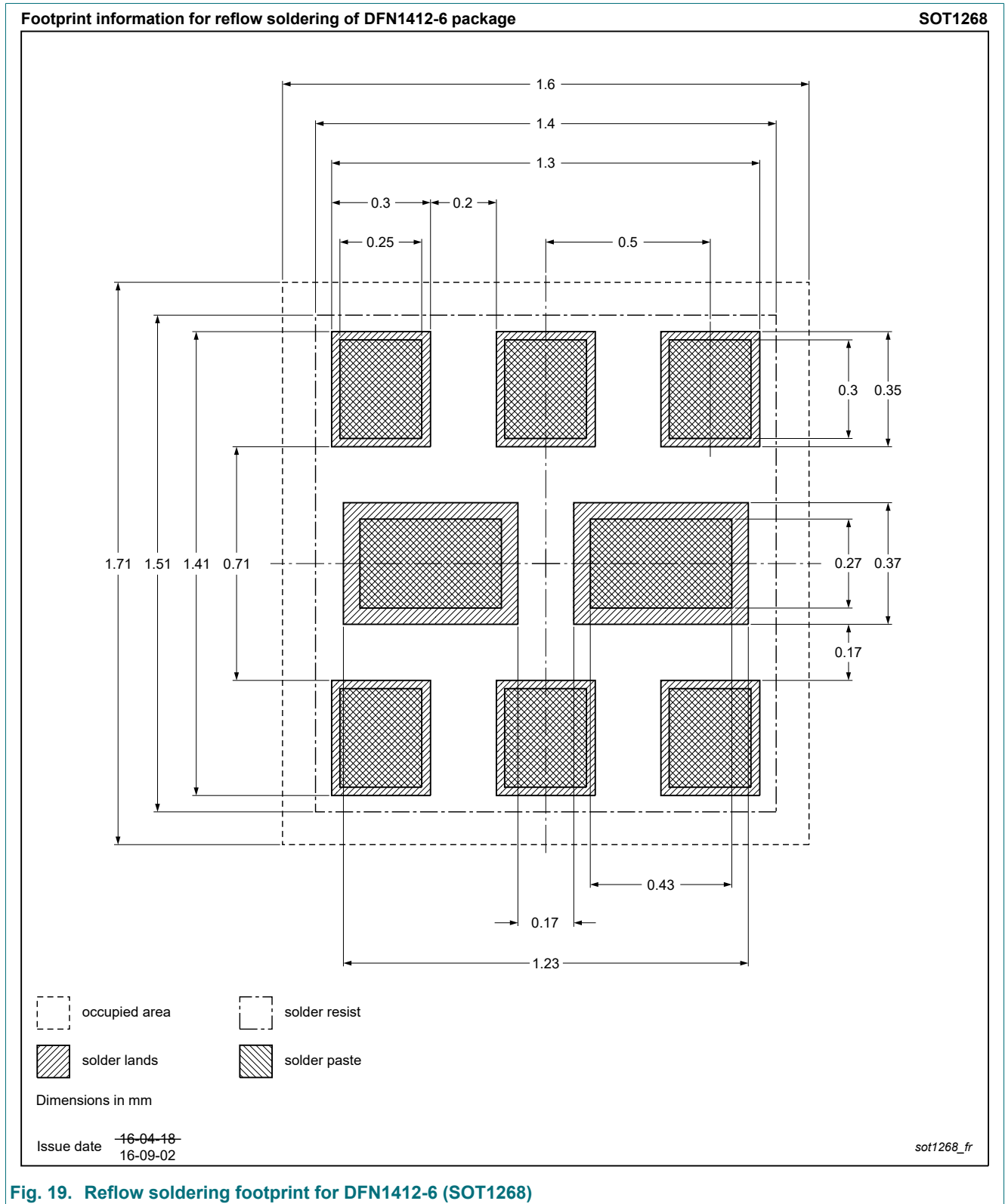


Fig. 19. Reflow soldering footprint for DFN1412-6 (SOT1268)

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BSS138AKRA-Q v.1	20240902	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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